

**Product data sheet** 

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Enhanced power dissipation capability of 940 mW
- ElectroStatic Discharge (ESD) protection > 2KV HBM
- AEC-Q101 qualified

### 3. Applications

- LED driver
- Power management
- Low-side loadswitch
- Switching circuits

### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	20	V
V <sub>GS</sub>	gate-source voltage	T <sub>j</sub> = 25 °C; T <sub>amb</sub> = 25 °C		-8	-	8	V
I <sub>D</sub>	drain current	$V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C	[1]	-	-	2.8	А
Static chara	acteristics		·	·			
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 4.5 V; I <sub>D</sub> = 2.8 A; T <sub>j</sub> = 25 °C		-	63	73	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



# 5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	G	gate	3	D			
2	S	source					
3	D	drain	1 2 TO-236AB (SOT23)	G G S 017aaa255			

# 6. Ordering information

Table 3. Ordering information						
Type number						
	Name	Description	Version			
PMV65UNEA	TO-236AB	plastic surface-mounted package; 3 leads	SOT23			

# 7. Marking

Table 4. Marking codes	
Type number	Marking code[1]
PMV65UNEA	EM%

[1] % = placeholder for manufacturing site code

# 8. Limiting values

 Table 5. Limiting values

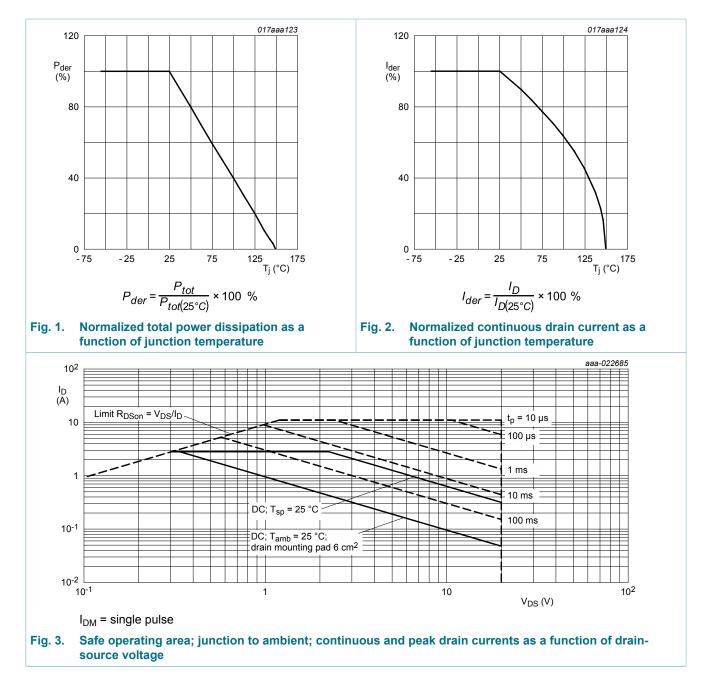
 In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	20	V
V <sub>GS</sub>	gate-source voltage	T <sub>j</sub> = 25 °C; T <sub>amb</sub> = 25 °C		-8	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	2.8	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	1.8	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	11	А
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$T_{j(init)}$ = 25 °C; I <sub>D</sub> = 0.3 A; DUT in avalanche (unclamped)		-	5.6	mJ
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	490	mW
			[1]	-	940	mW
		T <sub>sp</sub> = 25 °C		-	6.25	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drain	n diode		·			
ls	source current	T <sub>amb</sub> = 25 °C	[1]	-	0.9	А
ESD Maximu	um rating					
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ		-	2000	V

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>. [1]

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint. [2]

#### 20 V, N-channel Trench MOSFET

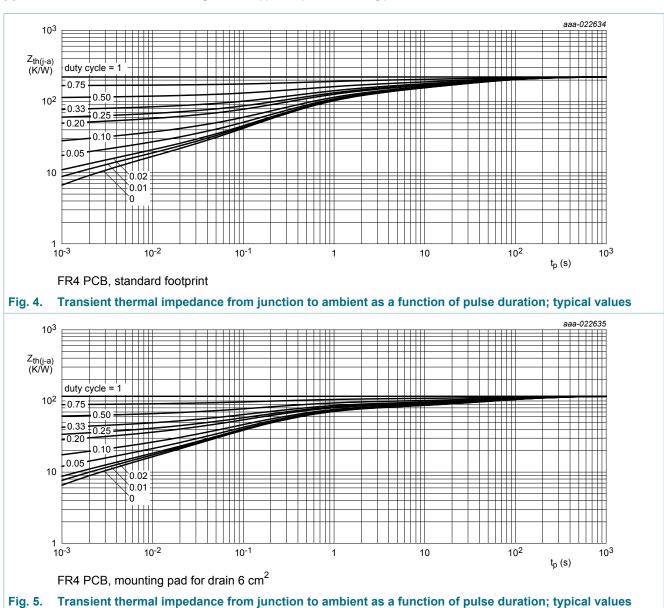


### 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	221	254	K/W
			[2]	-	116	133	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	17	20	K/W

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Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
 Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

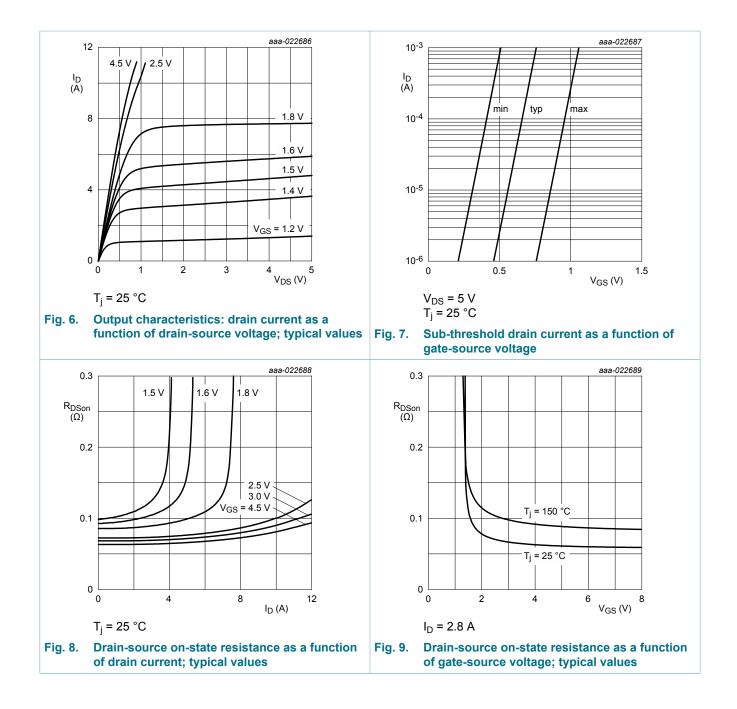
### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = 250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	0.45	0.7	1	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 20 V; V <sub>GS</sub> = 0 V	-	-	1	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	10	μA
		$V_{GS}$ = -8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-10	μA
		V <sub>GS</sub> = 4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	5	μA
		V <sub>GS</sub> = -4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-5	μA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 2.8 A; T <sub>j</sub> = 25 °C	-	63	73	mΩ
		$V_{GS}$ = 4.5 V; I <sub>D</sub> = 2.8 A; T <sub>j</sub> = 150 °C	-	93	108	mΩ
		$V_{GS}$ = 2.5 V; I <sub>D</sub> = 2.4 A; T <sub>j</sub> = 25 °C	-	71	83	mΩ
		V <sub>GS</sub> = 1.8 V; I <sub>D</sub> = 0.8 A; T <sub>j</sub> = 25 °C	-	83	94	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 3 A; T <sub>j</sub> = 25 °C	-	11	-	S
R <sub>G</sub>	gate resistance	T <sub>j</sub> = 25 °C; f = 1 MHz	-	1.8	-	Ω
Dynamic ch	naracteristics					
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 10 V; $I_{D}$ = 2.8 A; $V_{GS}$ = 4.5 V;	-	3.8	6	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.3	-	nC
Q <sub>GD</sub>	gate-drain charge		-	0.9	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 10 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	291	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	52	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	43	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 10 V; $I_D$ = 2.8 A; $V_{GS}$ = 4.5 V;	-	8	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	23	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	35	-	ns
t <sub>f</sub>	fall time		-	12	-	ns
Source-dra	in diode	· · · · · · · · · · · · · · · · · · ·				
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 0.9 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	0.7	1.2	V

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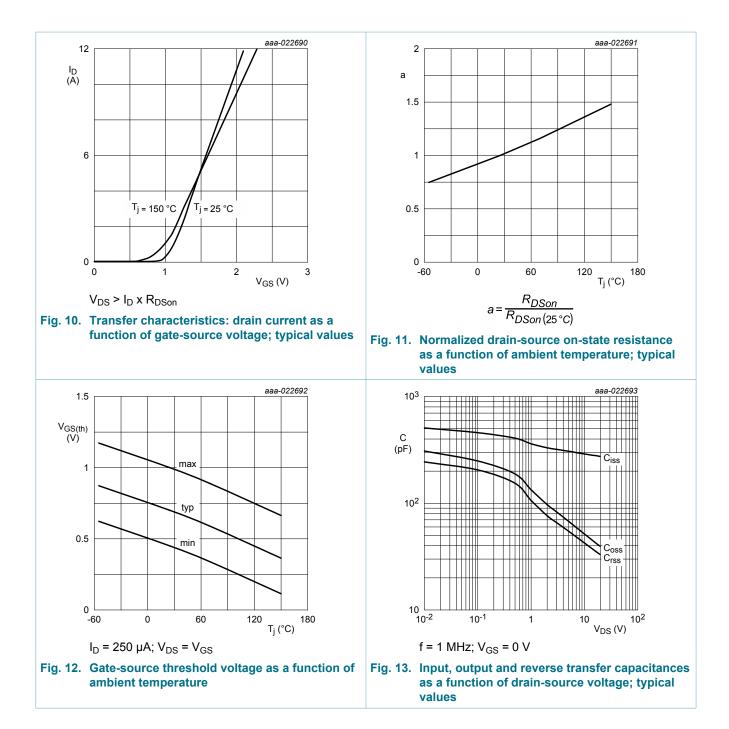


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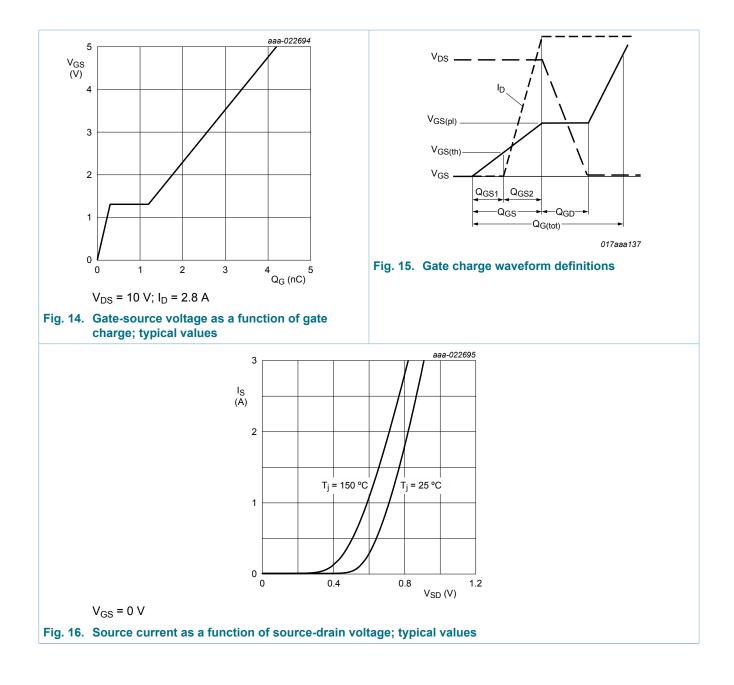
#### 20 V, N-channel Trench MOSFET



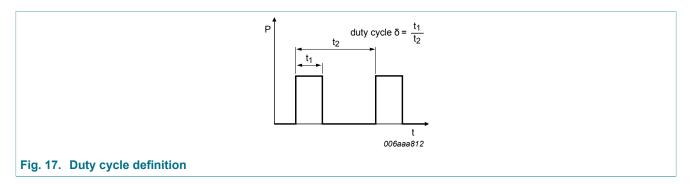
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#### 20 V, N-channel Trench MOSFET



### 11. Test information



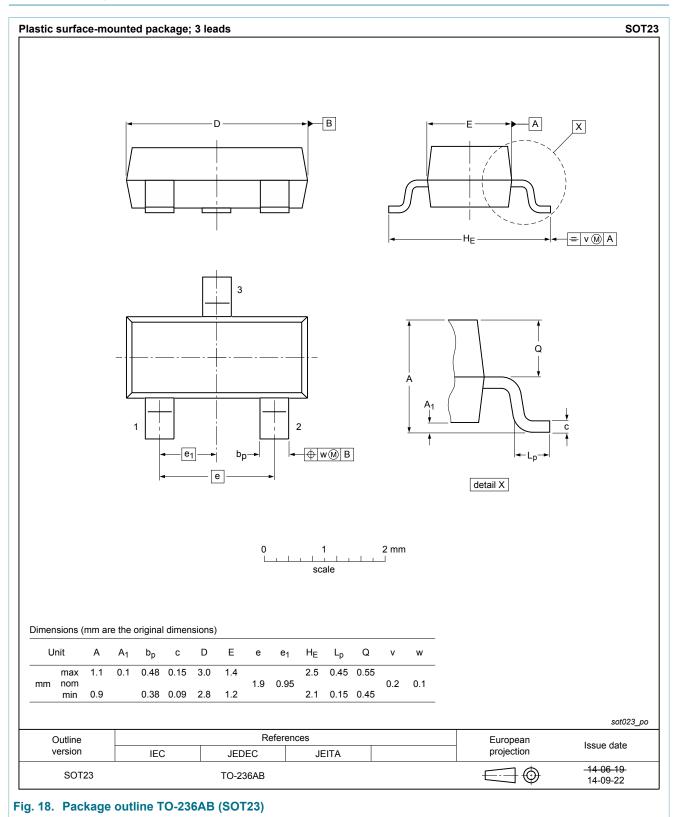
### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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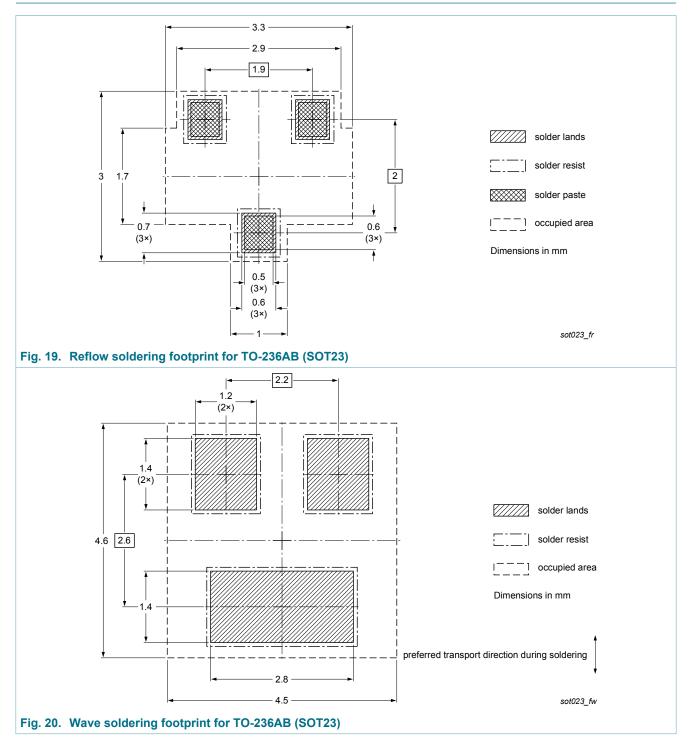
### 12. Package outline



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#### 20 V, N-channel Trench MOSFET

### 13. Soldering



# 14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMV65UNEA v.1	20170317	Product data sheet	-	-			

#### 20 V, N-channel Trench MOSFET

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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